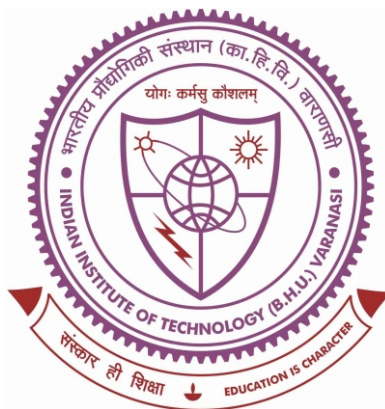


Nanoscale charge heterogeneity and chaotic resistive switching in VO₂-based Mott memristors



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By

Pawan Kumar Ojha

SCHOOL OF MATERIALS SCIENCE & TECHNOLOGY
INDIAN INSTITUTE OF TECHNOLOGY
(BANARAS HINDU UNIVERSITY)
VARANASI - 221005
INDIA

Roll No. 18111503

2024